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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.	
10/035,247	01/04/2002	Sang Hyun Yi	262/009	2931	
75	90 05/09/2003				
LEE & STERBA, P. C. 1101 Wilson Boulrvard Suite 2000			EXAMINER		
			WILSON, CHRISTIAN D		
Arlington, VA	22209	•	ART UNIT	PAPER NUMBER	
			2824		
		•	DATE MAILED: 05/09/2003	DATE MAILED: 05/09/2003	

Please find below and/or attached an Office communication concerning this application or proceeding.

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	Application No.	Applicant(s)	
	10/035,247	YI ET AL.	
Office Action Summary	Examin r	Art Unit	
•	Christian Wilson	2824	
The MAILING DATE of this communication app Period for Reply	ears on the cover sheet with the c	orrespond nce address	
A SHORTENED STATUTORY PERIOD FOR REPLY THE MAILING DATE OF THIS COMMUNICATION.  - Extensions of time may be available under the provisions of 37 CFR 1.13 after SIX (6) MONTHS from the mailing date of this communication.  - If the period for reply specified above is less than thirty (30) days, a reply - If NO period for reply is specified above, the maximum statutory period who is a reply within the set or extended period for reply will, by statute, any reply received by the Office later than three months after the mailing earned patent term adjustment. See 37 CFR 1.704(b).  Status	36(a). In no event, however, may a reply be ting within the statutory minimum of thirty (30) day will apply and will expire SIX (6) MONTHS from a cause the application to become ABANDONE	nely filed  rs will be considered timely. I the mailing date of this communication. D (35 U.S.C. § 133).	
1) Responsive to communication(s) filed on	<u> </u>		
,-	is action is non-final.		
3) Since this application is in condition for alloward closed in accordance with the practice under Disposition of Claims	nnce except for formal matters, p Ex parte Quayle, 1935 C.D. 11, 4	rosecution as to the merits is 153 O.G. 213.	
4)⊠ Claim(s) <u>1-28</u> is/are pending in the application	l <b>.</b>		
4a) Of the above claim(s) <u>18-28</u> is/are withdraw			
5) Claim(s) is/are allowed.			
6)⊠ Claim(s) <u>1-17</u> is/are rejected.			
7) Claim(s) is/are objected to.			
8) Claim(s) are subject to restriction and/o	r election requirement.		
Application Papers			
9) The specification is objected to by the Examine		–	
10)⊠ The drawing(s) filed on <u>04 January 2002</u> is/are:			
Applicant may not request that any objection to the			
11) The proposed drawing correction filed on		oved by the Examiner.	
If approved, corrected drawings are required in rep			
12) The oath or declaration is objected to by the Ex	ammer.		
Priority under 35 U.S.C. §§ 119 and 120		a) (d) as (f)	
13)  Acknowledgment is made of a claim for foreign	n priority under 35 0.5.C. § 119(8	1)-(u) or (i).	
a) ☑ All b) ☐ Some * c) ☐ None of:	a have been received		
<ul><li>1. Certified copies of the priority documents</li><li>2. Certified copies of the priority documents</li></ul>		ion No	
<ul><li>2.  Certified copies of the priority documents</li><li>3.  Copies of the certified copies of the priority</li></ul>			
application from the International Bu * See the attached detailed Office action for a list	reau (PCT Rule 17.2(a)).		
14) ☐ Acknowledgment is made of a claim for domesti	c priority under 35 U.S.C. § 119(	e) (to a provisional application)	).
<ul> <li>a)  The translation of the foreign language pro</li> <li>15)  Acknowledgment is made of a claim for domesting</li> </ul>			
Attachment(s)			
<ol> <li>Notice of References Cited (PTO-892)</li> <li>Notice of Draftsperson's Patent Drawing Review (PTO-948)</li> <li>Information Disclosure Statement(s) (PTO-1449) Paper No(s) 3</li> </ol>	5) Notice of Informal	y (PTO-413) Paper No(s) Patent Application (PTO-152) ory .	
S. Patent and Trademark Office			

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### **DETAILED ACTION**

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#### Election/Restrictions

- 1. Applicant's election without traverse of claims 1 17 in Paper No. 6 is acknowledged.
- 2. Claims 18 28 are withdrawn from further consideration pursuant to 37 CFR 1.142(b) as being drawn to a nonelected invention, there being no allowable generic or linking claim.

  Election was made without traverse in Paper No. 6.

## Claim Rejections - 35 USC § 102

3. The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

- (b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.
- 4. Claims 1 9 are rejected under 35 U.S.C. 102(b) as being anticipated by Ozawa.

Regarding claim 1, Ozawa (US 4,467,345) discloses a semiconductor device [Figure 4A] comprising a plurality of metal line patterns 8 having a predetermined surface area where two adjacent metal line patterns are spaced apart from each other at a predetermined distance.

Regarding claims 2 and 3, Ozawa further discloses that the distance is greater than 1.0  $\mu m$  and 1.5  $\mu m$  [column 4, line 25].

Regarding claim 4, Ozawa further discloses that the area is greater than 30  $\mu$ m by 30  $\mu$ m [column 4, lines 25-28].

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Regarding claim 5, Ozawa discloses a semiconductor device [Figure 4A] comprising a metal line layer [Figure 4B] with a plurality of metal line patterns 8 spaced apart from each other and an underlying layer 6 under the metal line layer. In response to applicant's claim that the spacing is sufficient to prevent a crack from occurring in the underlying layer, a recitation of the intended use of the claimed invention must result in a structural difference between the claimed invention and the prior art in order to patentably distinguish the claimed invention from the prior art. If the prior art structure is capable of performing the intended use, then it meets the claim. See *In re Casey*, 152 USPQ 235 (CCPA 1967) and *In re Otto*, 136 USPQ 458, 459 (CCPA 1963). Since there is no difference between the claimed structure and the device in Ozawa, the claimed intended use does not patentably distinguish the claimed invention from the prior art. Further, Ozawa anticipates the use of the disclosed invention to prevent crack formation [column 2, lines 20-25, 53-55].

Regarding claims 6 and 7, Ozawa further discloses that the distance is greater than 1.0 µm and 1.5 µm [column 4, line 25].

Regarding claim 8, Ozawa further discloses an underlying insulating layer [column 3,line 52].

Regarding claim 9, Ozawa further discloses that the area is greater than 30  $\mu$ m by 30  $\mu$ m [column 4, lines 25-28].

### Claim Rejections - 35 USC § 103

5. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

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(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

6. Claims 10 – 12 and 14 – 16 are rejected under 35 U.S.C. 103(a) as being unpatentable over Ozawa in view of Hara *et al.* 

Regarding claim 10, Ozawa teaches a semiconductor device [Figure 4A] comprising a plurality of metal line patterns 8 where two adjacent metal line patterns are spaced apart from each other. Hara et al. (US 5,229,642) teaches a semiconductor device [Figure 5] where in an adjacent metal line pattern, one pattern has a slit 13. It would have been obvious to one of ordinary skill in the art to combine the metal slit of Hara et al. with the metal line pattern of Ozawa since the slit reduces the effective width of the line and prevents cracks [column 2, lines 41-45].

Regarding claim 11, Hara *et al.* further teaches a slit with a width greater than 1.0  $\mu$ m [column 5, lines 1-5]. It would have been obvious to one of ordinary skill in the art to use a slit with a width greater than 1.0  $\mu$ m since this width prevents the increase of the resistance of the metal line.

Regarding claim 12, Hara *et al.* further teaches a slit formed at a predetermined distance from the edge of the metal line pattern [Figure 5]. It would have been obvious to one of ordinary skill in the art to form the slit at a distance from the edge of the pattern since this reduces the stress in the metal line layer and eliminates cracks [column 5, lines 20-25].

Regarding claim 14, Ozawa teaches a semiconductor device [Figure 4A] comprising a metal line layer [Figure 4B] with a plurality of metal line patterns 8 spaced apart from each other and an underlying layer 6 under the metal line layer. Hara *et al.* teaches a semiconductor device

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[Figure 5] where in an adjacent metal line pattern, one pattern has a slit 13. It would have been obvious to one of ordinary skill in the art to combine the metal slit of Hara *et al.* with the metal line pattern of Ozawa since the slit reduces the effective width of the line and prevents cracks [column 2, lines 41-45].

Regarding claims 15 and 16, Hara *et al.* further teaches a slit parallel to the space between the adjacent metal line patterns with a width greater than 1.0 µm [column 5, lines 1-5]. It would have been obvious to one of ordinary skill in the art to use a slit with a width greater than 1.0 µm parallel to the space between the adjacent metal line patterns since this configuration prevents the increase of the resistance of the metal line and eliminates cracks.

7. Claims 13 and 17 are rejected under 35 U.S.C. 103(a) as being unpatentable over Ozawa in view of Hara et al. as applied to claims 12 and 14 above, and further in view of Matsukawa.

Ozawa as modified by Hara *et al.* teaches the limitations of claims 12 and 14 as described above. Matsukawa (US 4,835,591) teaches a slit in an adjacent metal line pattern which is spaced less than 4 µm from the edge of the metal line pattern [column 4, line 66]. It would have been obvious to one of ordinary skill in the art to use this distance for the metal slit of Hara *et al.* in the device of Ozawa since this distance prevents the formation of hillocks on the metal line [column 4, lines 67-68].

#### Conclusion

8. A copy of the EAST search history is included in this office action.

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9. Any inquiry concerning this communication or earlier communications from the examiner should be directed to Christian Wilson whose telephone number is (703) 308-6265. The examiner can normally be reached on weekdays, 7:30 AM to 4 PM.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Richard Elms can be reached on (703) 308-2816. The fax phone numbers for the organization where this application or proceeding is assigned are (703) 308-7722 for regular communications and (703) 308-7724 for After Final communications.

Any inquiry of a general nature or relating to the status of this application or proceeding should be directed to the receptionist whose telephone number is (703) 308-0658.

Christian Wilson, Ph.D. Examiner Art Unit 2824

CDW May 6, 2003

> Vu A. Le Primary Examiner

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